ZHCSQO2N - AUGUST 1998 - REVISED FEBRUARY 2025

# CD405xB 具有逻辑电平转换功能的 CMOS 单路 8 通道 模拟多路复用器或多路信号分离器

## 1 特性

• 各种数字和模拟信号电平:

- 数字: 3V 至 20V - 模拟:≤20V<sub>P-P</sub>

• 单电源范围: 3V至 20V(VDD < 3V时,性能会下

• 双电源范围: ±3V 至 ±10V

• 在 V<sub>DD</sub> = 15V 时,输入范围内的低导通电阻为 125Ω (典型值)

在 V<sub>DD</sub> = 15V 时,低通道漏电流为 ±10pA (典型

低静态功耗:0.2µW(典型值)

• 先断后合开关消除了通道重叠

• 双向信号路径

• ESD 保护 HBM: 3000V, CDM: 2000V • 与业界通用 4051 多路复用器兼容的引脚

## 2 应用

- 模拟和数字多路复用和多路信号分离
- 模数和数模转换
- 信号门控
- 工厂自动化
- 电视
- 电器
- 消费类音频
- 可编程逻辑电路
- 传感器

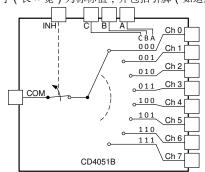
## 3 说明

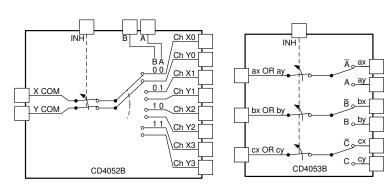
CD405xB 模拟多路复用器和多路信号分离器是数字控 制的模拟开关,具有低接通阻抗和极低的关断漏电流。 这些多路复用器电路在整个 VDD - VSS 和 VDD - VEE 电源电压范围内,消耗的静态功率极低,而不受控制信 号的逻辑状态影响。

封装信息

器件型号	封装 <sup>(1)</sup>	封装尺寸 <sup>(2)</sup>		
CD405xB	J ( CDIP、16 )	19.50mm × 6.92mm		
	N ( PDIP , 16 )	19.3mm × 9.4mm		
	D ( SOIC , 16 )	9.9mm × mm		
	NS ( SOP , 16 )	10.2mm × 7.8mm		
	PW (TSSOP, 16)	5mm × 6.4mm		

- (1) 如需了解所有可用封装,请参阅数据表末尾的可订购产品附
- (2) 封装尺寸(长×宽)为标称值,并包括引脚(如适用)。





CD4051B 的功能图



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## 4 Pin Configuration and Functions

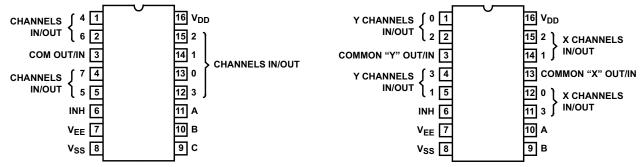


图 4-1. CD4051B E, M, NS, and PW Package, 16-Pin 图 4-2. CD4052B E, M, NS, and PW Package, 16-Pin PDIP, CDIP, SOIC, SOP, and TSSOP (Top View) PDIP, CDIP, SOP, and TSSOP (Top View)

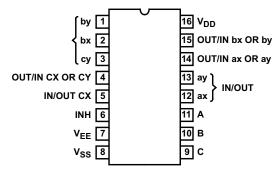


图 4-3. CD4053B E, M, NS, and PW Package, 16-Pin PDIP, CDIP, SOP, and TSSOP (Top View)

表 4	4-1.	Pin	Fun	ctions	s CD4	1051B

PIN		TYPE <sup>(1)</sup>	DESCRIPTION			
NO.	NAME	ITPE(*/	DESCRIPTION			
1	CH 4 IN/OUT	I/O	Channel 4 in/out			
2	CH 6 IN/OUT	I/O	Channel 6 in/out			
3	COM OUT/IN	I/O	Common out/in			
4	CH 7 IN/OUT	I/O	Channel 7 in/out			
5	CH 5 IN/OUT	I/O	hannel 5 in/out			
6	INH	I	sables all channels. See 表 7-1.			
7	V <sub>EE</sub>	_	Negative power input			
8	V <sub>SS</sub>	_	Ground			
9	С	I	Channel select C. See 表 7-1.			
10	В	I	Channel select B. See 表 7-1.			
11	A	1	Channel select A. See 表 7-1.			
12	CH 3 IN/OUT	I/O	Channel 3 in/out			
13	CH 0 IN/OUT	I/O	Channel 0 in/out			
14	CH 1 IN/OUT	I/O	Channel 1 in/out			
15	CH 2 IN/OUT	I/O	Channel 2 in/out			
16	V <sub>DD</sub>	_	Positive power input			

<sup>(1)</sup> I = input, O = output



## 表 4-2. Pin Functions CD4052B

	PIN	TYPE <sup>(1)</sup>	DESCRIPTION			
NO.	NAME	TIPE(")	DESCRIPTION			
1	Y CH 0 IN/OUT	I/O	Channel Y0 in/out			
2	Y CH 2 IN/OUT	I/O	Channel Y2 in/out			
3	Y COM OUT/IN	I/O	Y common out/in			
4	Y CH 3 IN/OUT	I/O	Channel Y3 in/out			
5	Y CH 1 IN/OUT	I/O	Channel Y1 in/out			
6	INH	I	isables all channels. See 表 7-1.			
7	V <sub>EE</sub>	_	Negative power input			
8	V <sub>SS</sub>	_	Ground			
9	В	I	Channel select B. See 表 7-1.			
10	A	I	Channel select A. See 表 7-1.			
11	X CH 3 IN/OUT	I/O	Channel X3 in/out			
12	X CH 0 IN/OUT	I/O	Channel X0 in/out			
13	X COM IN/OUT	I/O	X common out/in			
14	X CH 1 IN/OUT	I/O	Channel in/out			
15	X CH 2 IN/OUT	I/O	Channel in/out			
16	$V_{DD}$		Positive power input			

#### (1) I = input, O = output

## 表 4-3. Pin Functions CD4053B

	PIN	TYPE <sup>(1)</sup>	DESCRIPTION		
NO.	NAME	ITPE	DESCRIPTION		
1	BY IN/OUT	I/O	B channel Y in/out		
2	BX IN/OUT	I/O	B channel X in/out		
3	CY IN/OUT	I/O	C channel Y in/out		
4	CX OR CY OUT/IN	I/O	C common out/in		
5	CX IN/OUT	I/O	C channel X in/out		
6	INH	1	sables all channels. See 表 7-1.		
7	V <sub>EE</sub>	_	Negative power input		
8	V <sub>SS</sub>	_	Ground		
9	С	1	Channel select C. See 表 7-1.		
10	В	1	Channel select B. See 表 7-1.		
11	A	1	Channel select A. See 表 7-1.		
12	AX IN/OUT	I/O	A channel X in/out		
13	AY IN/OUT	I/O	A channel Y in/out		
14	AX OR AY OUT/IN	I/O	A common out/in		
15	BX OR BY OUT/IN	I/O	B common out/in		
16	$V_{DD}$		Positive power input		

<sup>(1)</sup> I = input, O = output

English Data Sheet: SCHS047

## **5 Specifications**

## 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1) (2)

			MIN	MAX	UNIT
	Supply Voltage	V+ to V-, Voltages Referenced to V <sub>SS</sub> Terminal	- 0.5	20	V
	DC Input Voltage		- 0.5	V <sub>DD</sub> +0.5	V
	DC Input Current	Any One Input	- 10	10	mA
T <sub>JMAX1</sub>	Maximum junction temperature, co	eramic package		175	°C
T <sub>JMAX2</sub>	Maximum junction temperature, plastic package			150	°C
T <sub>stg</sub>	Storage temperature		- 65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Rating may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Condition. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltages are with respect to ground, unless otherwise specified.

#### 5.2 ESD Ratings

			VALUE	UNIT
V Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/ JEDEC JS-001, all pins <sup>(1)</sup>	±3000	V	
V <sub>(ESD)</sub>	SD) Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup>	±2000	V

<sup>(1)</sup> JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.

## 5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		J (	,				
				MIN	NOM	MAX	UNIT
Temperatu	re Range			- 55		125	°C

#### 5.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>			CD405x				
		E (PDIP)	E (PDIP) M (SOIC) NS (SOP) PW (TSSO		PW (TSSOP)	UNIT	
		16 PINS	16 PINS	16 PINS	16 PINS		
R <sub>0</sub> JA	Junction-to-ambient thermal resistance	67	73	64	116.5	°C/W	

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

<sup>(2)</sup> JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.



## **5.5 Electrical Characteristics**

PARAMETER		TEST CONDITIONS					TYP N	IAX	UNI
SIGNAL INPUTS (V <sub>IS</sub> ) AND OUTPUT	S (V <sub>OS</sub> )					•			
	V <sub>IS</sub> (V)	V <sub>EE</sub> (V)	V <sub>SS</sub> (V)	V <sub>DD</sub> (V)	TEMP				
					- 55°C			60	_
					- 40°C			60	
		0V	0V	5V	25°C		17	60	
					85°C			150	
					125°C			150	
					- 55°C			60	
					- 40°C			60	
		0V	0V	10V	25°C		18	60	
					85°C			300	
Quiescent Device Current, I <sub>DD</sub> Max					125°C			300	
					- 55°C			60	μA
					- 40°C			60	
		0V	0V	15V	25°C		18	60	1
				85°C			600	1	
					125°C			600	0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0
					- 55°C			100	
					- 40°C			100	
		0V	0V	20V	25°C		18	100	
					85°C		3	000	
					125°C		3	000	
				5V	- 55°C			800	) ) )
					- 40°C			850	
		0V	0V		25°C		470 1	050	
					85°C		1	200	
					125°C		1	300	
					- 55°C			310	
rain to Source ON Resistance r <sub>ON</sub>			0V		- 40°C			300	Ω Ω Ω Ω Ω Ω Ω Ω Ω Ω Ω Ω Ω Ω Ω Ω Ω Ω Ω
lax		0V		10V	25°C		180	400	
$\leqslant V_{IS} \leqslant V_{DD}$					85°C			520	
					125°C			550	
					- 55°C			200	
				15V	- 40°C			210	
		0V	0		25°C		125	240	
					85°C			300	
					125°C			300	
change in ON Resistance		0V	0V	5V			15		
Between Any Two Channels),		0V	0V	10V	25°C		10		Ω
A R <sub>ON</sub>		0V	0V	15V			5		



# 5.5 Electrical Characteristics (续)

	PARAMETER			٦	TEST COND	DITIONS		MIN TYP MAX	UNIT
							- 55°C	± 100	)
							- 40°C	± 100	)
	nannel Leakage Curre el OFF (Max)	ent: Any		25°C		± 0.3 100 (2	)		
or ALL	Channels OFF (COM I) (Max)	MON		0V	0V	18V	85°C	1000	)
							125°C	1000	
	ON Channel Leakage Current: Any		5 or 0	- 5V	0V	10.5V	85°C	± 300	)
ALL Ch (Max)	Channel ON (Max) or LL Channels ON (COMMON OUT/IN) Max)		5	0V	0V	18V	85°C	± 300	nA
	Input, C <sub>IS</sub>							5	
	Output, C <sub>OS</sub>	CD4 051						30	
Capaci tance	Output, C <sub>OS</sub>	CD4 052		0V	0V	10V	25°C	18	pF
	Output, C <sub>OS</sub>	CD4 053						9	
	Feed through, C <sub>IOS</sub>							0.2	
	'			R <sub>L</sub> = 200k Ω		5V		30 60	)
Prop D	elay		$V_{DD}$	C <sub>L</sub> = 50pF		10V	25°C	15 30	0 ns
				$t_{r}, t_{f} = 20 \text{ns}$		15V		10 20	)



## 5.5 Electrical Characteristics (续)

	PARAMETER		$_{\text{L}} = 100  \Omega$ , (unless otherwise noted TEST CONDITIONS						UNIT
CONT	ROL (ADDRESS OR INHIBIT), V	/c							
						- 55°C	0.	8	
						- 40°C	0.	8	1
					5V	25°C		0.8	
						85°C	0.	8	
						125°C	0.	8	
						- 55°C	0.	8	
						- 40°C	0.	8	
nput L	ow Voltage, V <sub>IL</sub> , Max				10V	25°C		0.8	V
						85°C	0.	8	
						125°C	0.	8	
						- 55°C	0.	0.8	
						- 40°C	0.	8	
					15V	25°C		0.8	
						85°C	0.	8	
						125°C	0.	8	
						- 55°C	3.	5	
					- 40°C	3.	5		
					5V	25°C	3.5		
						85°C	3.	5	
						125°C	3.	5	
						- 55°C		7	
						- 40°C		7	
Input H	igh Voltage, V <sub>IH</sub> , Min				10V	25°C	7	,	V
						85°C		7	
						125°C		7	
						- 55°C	1	1	
						- 40°C	1	1	
					15V	25°C	11		
						85°C	1	1	
						125°C	1	1	
						- 55°C		±1	
						- 40°C		±1	
Input c	nput current, I <sub>IN</sub> (Max)	V <sub>IN</sub> = 0, 18	V <sub>IN</sub> = 0, 18			25°C	±0.	6 ±1	μA
					85°C		±1		
						125°C		±1	
Propa	Address-to-Signal OUT		0V	0V	5V		45	720	
gation	(Channels ON or OFF) (See	$t_r$ , $t_f = 20$ ns, $C_L = 50$ pF,	0V	0V	10V		16		ne
Delay Time	Figure 10, Figure 11, and Figure 15)	$R_L = 10k \Omega$	0V	0V	15V		12		
	1 19410 10/		- 5V	0V	5V		22	5 450	



## 5.5 Electrical Characteristics (续)

-	PARAMETER	3 7 3011		EST CONDITI	IONS	,	MIN	TYP	MAX	UNIT
Propa			0V	0V	5V			400	720	
gation	Inhibit-to-Signal OUT (Channel	$t_r$ , $t_f = 20$ ns, $C_L = 50$ pF,	0V	0V	10V			160	320	no
Delay	Turning ON) (See Figure 11)	$R_{l} = 1k\Omega$	0V	0V	15V			120	240	ns
Time			- 10V	0V	5V			200	400	
Propa			0V	0V	5V			200	450	
gation	Inhibit-to-Signal OUT (Channel	$t_{\rm r}$ , $t_{\rm f} = 20  \rm ns$ ,	0V	0V	10V			90	210	
Delay Time	Turning OFF) (See Figure 17)	$C_L = 50 pF,$ $R_L = 10 k \Omega$	0V	0V	15V			70	160	ns
Time		_	- 10V	0V	5V			130	300	
Input Ca	Input Capacitance, C <sub>IN</sub> (Any Address or Inhibit Input)			0V	5V	25°C		5	7.5	pF

 <sup>(1)</sup> Peak-to-Peak voltage symmetrical about (V<sub>DD</sub> - V<sub>EE</sub>) / 2.
 (2) Determined by minimum feasible leakage measurement for automatic testing.

#### **5.6 AC Performance Characteristics**

 $V_{DD}$  = +15V,  $V_{SS}$  =  $V_{EE}$  = 0V,  $T_A$  = 25  $^{\circ}$ C (unless otherwise noted)

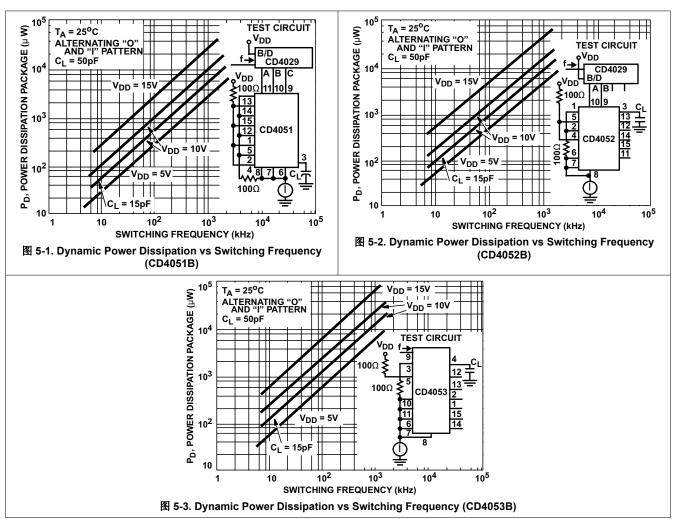
PARAMETER			TEST	CONDITIONS		TYP	UNIT
	V <sub>IS</sub> (V)	V <sub>DD</sub> (V)	R <sub>L</sub> (kΩ)				
		10	1		CD4053	30	
Cutoff ( - 3dB)	5 <sup>(1)</sup>	10	1	V <sub>OS</sub> at Common OUT/IN	CD4052	25	
Frequency Channel ON (Sine Wave		10	1		CD4051	20	MHz
Input)	$V_{EE} = V_{SS}$ , 20Log( $V_{OS}/V$	′ <sub>IS</sub> ) = - 3dB		V <sub>OS</sub> at Any Channel		60	
	2 <sup>(1)</sup>	5	10			0.3%	
Total Harmonic	3 <sup>(1)</sup>	10	10			0.2%	%
Distortion, THD	5 <sup>(1)</sup>	15	10			0.12%	70
	V <sub>EE</sub> = V <sub>SS</sub> , f <sub>IS</sub>	s = 1kHz Sine	Wave				
- 40dB Feedthrough Frequency (All Channels OFF)	5 <sup>(1)</sup>	10	1	V <sub>OS</sub> at Common OUT/IN	CD4053	8	
,					CD4052	10	MHz
	V <sub>EE</sub> = V <sub>SS</sub> , 20Log(V <sub>OS</sub> /V	/ ) = _ 40dB			CD4051	12	
	ZULUG(VOS/V	IS) - 400D		V <sub>OS</sub> at Any Channel		8	
	5 <sup>(1)</sup>	10	1			3	
		1		Detugen Coefficie	Measured on Common	6	
- 40dB Signal Crosstalk Frequency	V <sub>EE</sub> = V <sub>SS</sub> ,	/ ) = 2dD		Between Sections, CD4052 Only	Measured on Any Channel	10	MHz
rioquency	20Log(V <sub>OS</sub> /V	(IS) = - 30B		Between Any Two	In Pin 2, Out Pin 14	2.5	
		Sections, CD4053 Only	In Pin 15, Out Pin 14	6			
Address-or-Inhibit-to-		10	10 <sup>(2)</sup>			65	${\sf mV}_{\sf PEAK}$
Signal Crosstalk	$V_{EE} = 0, V_{SS}$ $V_{CC} = V_{DD}$		0ns, mVPEAK e Wave)			65	$mV_{PEAK}$

<sup>(1)</sup> Peak-to-Peak voltage symmetrical about ( $V_{DD}$  -  $V_{EE}$ ) / 2. (2) Both ends of channel.

English Data Sheet: SCHS047



## 5.7 Typical Characteristics



## **6 Parameter Measurement Information**

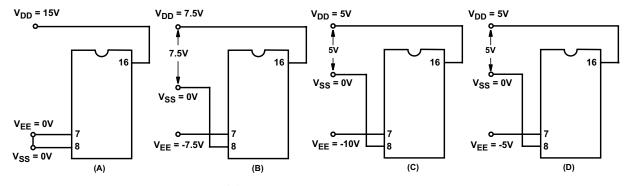


图 6-1. Typical Bias Voltages

备注

The ADDRESS (digital-control inputs) and INHIBIT logic levels are:  $0 = V_{SS}$  and  $1 = V_{DD}$ . The analog signal (through the TG) may swing from  $V_{EE}$  to  $V_{DD}$ .



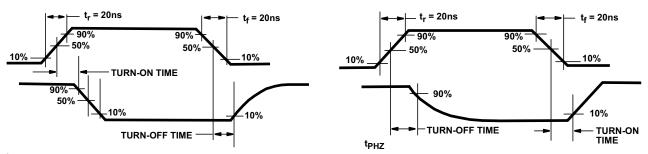


图 6-2. Waveforms, Channel Being Turned ON ( $R_L$  = 图 6-3. Waveforms, Channel Being Turned OFF ( $R_L$  1k  $\Omega$ )

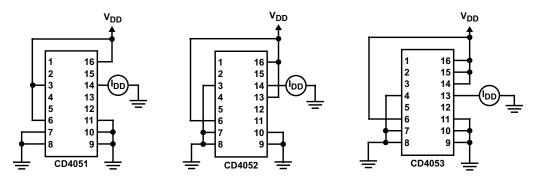


图 6-4. OFF Channel Leakage Current - Any Channel OFF

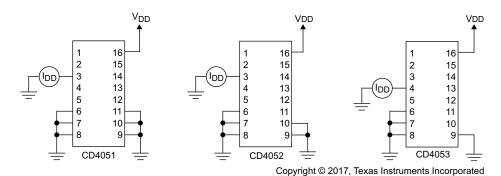


图 6-5. On Channel Leakage Current - Any Channel On

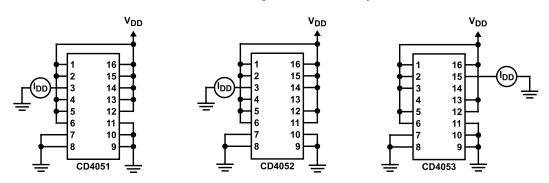


图 6-6. OFF Channel Leakage Current - All Channels OFF

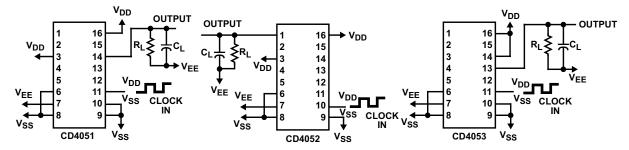


图 6-7. Propagation Delay - Address Input to Signal Output

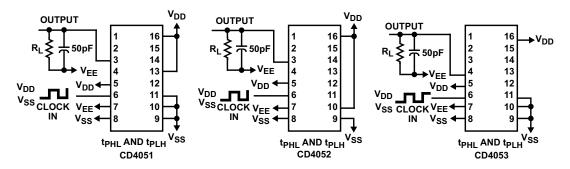


图 6-8. Propagation Delay - Inhibit Input to Signal Output

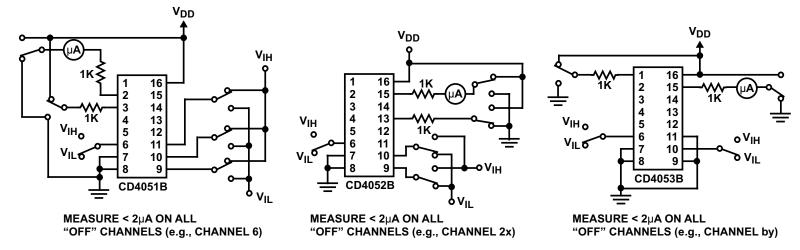


图 6-9. Input Voltage Test Circuits (Noise Immunity)



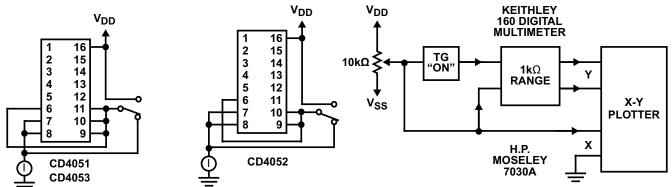
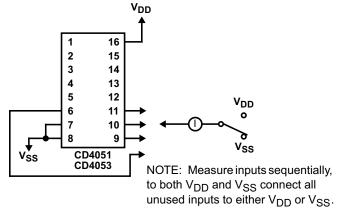


图 6-10. Quiescent Device Current

图 6-11. Channel ON Resistance Measurement Circuit



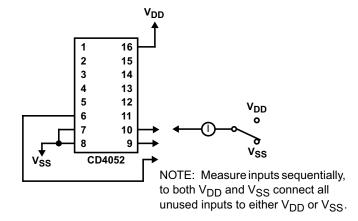


图 6-12. Input Current

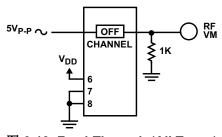


图 6-13. Feed-Through (All Types)

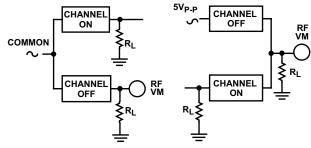
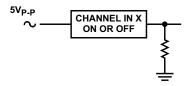


图 6-14. Crosstalk Between Any Two Channels (All Types)



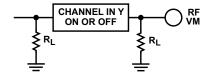
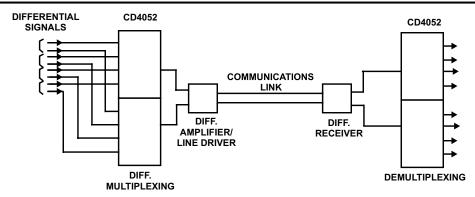


图 6-15. Crosstalk Between Duals or Triplets (CD4052B, CD4053B)



Special Considerations: In applications where separate power sources are used to drive V<sub>DD</sub> and the signal inputs, the V<sub>DD</sub> current capability should exceed V<sub>DD</sub>/R<sub>L</sub> (R<sub>L</sub> = effective external load). This provision avoids permanent current flow or clamp action on the V<sub>DD</sub> supply when power is applied or removed from the CD4051B, CD4052B or CD4053B.

#### 图 6-16. Typical Time-Division Application of the CD4052B

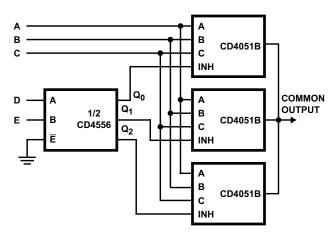


图 6-17. 24-to-1MUX Addressing

## 7 Detailed Description

#### 7.1 Overview

The CD4051B device is a single 8-channel multiplexer having three binary control inputs, A, B, and C, and an inhibit input. The three binary signals select 1 of 8 channels to be turned on, and connect one of the 8 inputs to the output.

The CD4052B device is a differential 4-channel multiplexer having two binary control inputs, A and B, and an inhibit input. The two binary input signals select 1 of 4 pairs of channels to be turned on and connect the analog inputs to the outputs.

The device is a triple 2-channel multiplexer having three separate digital control inputs, A, B, and C, and an inhibit input. Each control input selects one of a pair of channels which are connected in a single-pole, doublethrow configuration.

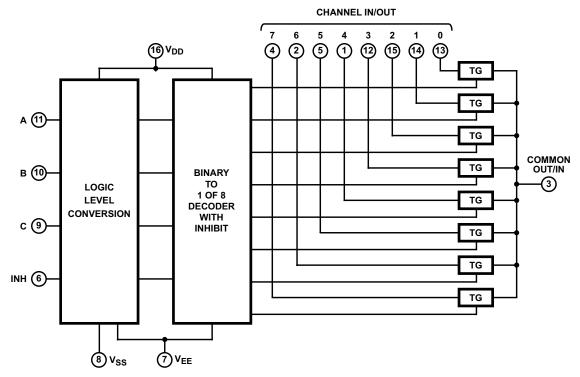
When these devices are used as demultiplexers, the CHANNEL IN/OUT terminals are the outputs and the COMMON OUT/IN terminals are the inputs.

Product Folder Links: CD4051B CD4052B CD4053B

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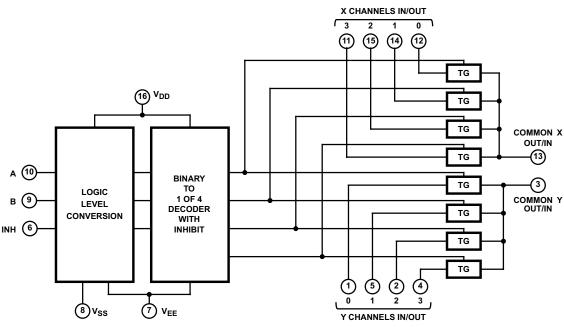


## 7.2 Functional Block Diagrams



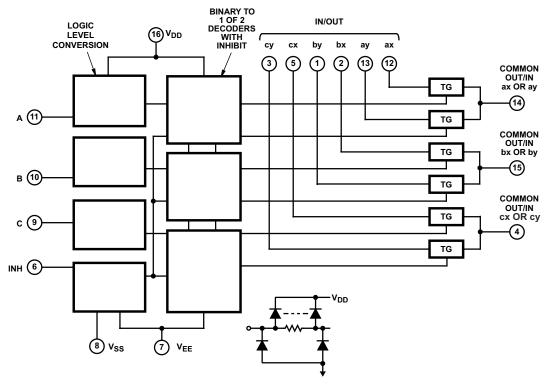
All inputs are protected by standard CMOS protection network.

图 7-1. Functional Block Diagram, CD4051B



All inputs are protected by standard CMOS protection network.

图 7-2. Functional Block Diagram, CD4052B



All inputs are protected by standard CMOS protection network.

图 7-3. Functional Block Diagram, CD4053B

## 7.3 Feature Description

The CD405xB line of multiplexers and demultiplexers can accept a wide range of digital and analog signal levels. Digital signals range from 3V to 20V, and analog signals are accepted at levels  $\leq$  20V. The devices have low ON resistance, typically 125 $\Omega$  over 15V<sub>P-P</sub> signal input range for V<sub>DD</sub> - V<sub>EE</sub> = 18V. This feature allows for very little signal loss through the switch.

The CD405xB devices also have high OFF resistance, which keeps from the devices from wasting power when the switch is in the OFF position, with typical channel leakage of  $\pm 100$ pA at  $V_{DD}$  -  $V_{EE}$  = 18V.

Binary address decoding on the chip makes channel selection simple. When channels are changed, a break-before-make system eliminates channel overlap.



## 7.4 Device Functional Modes

表 7-1. Truth Table (1)

	IN	PUT STATES		ON CHANNEL (C)
INHIBIT	С	В	Α	ON CHANNEL(S)
CD4051B	-			
0	0	0	0	0
0	0	0	1	1
0	0	1	0	2
0	0	1	1	3
0	1	0	0	4
0	1	0	1	5
0	1	1	0	6
0	1	1	1	7
1	Х	Х	X	None
CD4052B	'			
0		0	0	0x, 0y
0		0	1	1x, 1y
0		1	0	2x, 2y
0		1	1	3x, 3y
1		Х	X	None
CD4053B				
0	X	Х	0	ax
0	Х	Х	1	ay
0	X	0	X	bx
0	X	1	X	by
0	0	Χ	X	сх
0	1	X	X	су
1	Х	X	Х	None

<sup>(1)</sup> X = Do not care

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## 8 Application and Implementation

## 备注

以下应用部分中的信息不属于 TI 器件规格的范围,TI 不担保其准确性和完整性。TI 的客 户应负责确定器件是否适用于其应用。客户应验证并测试其设计,以确保系统功能。

#### 8.1 Application Information

The CD405xB multiplexers and demultiplexers can be used for a wide variety of applications.

#### 8.2 Typical Application

One application of the CD4051B is to use it in conjunction with a microcontroller to poll a keypad. 8 8-1 shows the basic schematic for such a polling system. The microcontroller uses the channel select pins to cycle through the different channels while reading the input to see if a user is pressing any of the keys. This application is a very robust setup, allowing for multiple simultaneous key-presses with very little power consumption. This setup also uses very few pins on the microcontroller. The down side of polling is that the microcontroller must continually scan the keys for a press and can do little else during this process.

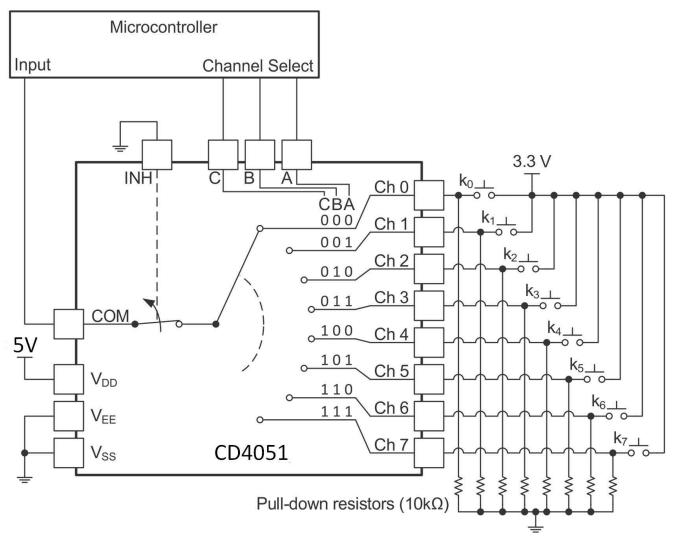


图 8-1. The CD4051B Being Used to Help Read Button Presses on a Keypad

#### 8.2.1 Design Requirements

These devices use CMOS technology and have balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads, so routing and load conditions should be considered to prevent ringing.

#### 8.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions:
  - For switch time specifications, see propagation delay times in Electrical Characteristics.
  - Inputs should not be pushed more than 0.5V above  $V_{DD}$  or below  $V_{FF}$ .
  - For input voltage level specifications for control inputs, see V<sub>IH</sub> and V<sub>II</sub> in *Electrical Characteristics*.
- 2. Recommended Output Conditions:
  - Outputs should not be pulled above V<sub>DD</sub> or below V<sub>EE</sub>.
- 3. Input or output current consideration:
  - The CD405xB series of parts do not have internal current drive circuitry and thus cannot sink or source current. Any current will be passed through the device.

#### 8.2.3 Application Curve

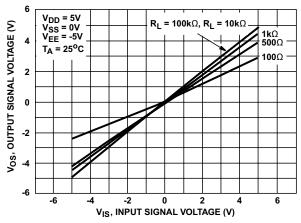


图 8-2. ON Characteristics for 1 of 8 Channels (CD4051B)

## 8.3 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the Electrical Characteristics.

Each V<sub>CC</sub> terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a  $0.1\,\mu$  F bypass capacitor is recommended. If there are multiple pins labeled  $V_{CC}$ , then a  $0.01\,\mu$  F or  $0.022 \,\mu\,\text{F}$  capacitor is recommended for each  $V_{CC}$  because the  $V_{CC}$  pins will be tied together internally. For devices with dual supply pins operating at different voltages, for example V<sub>CC</sub> and V<sub>DD</sub>, a 0.1µF bypass capacitor is recommended for each supply pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. 0.1 µ F and 1 µ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

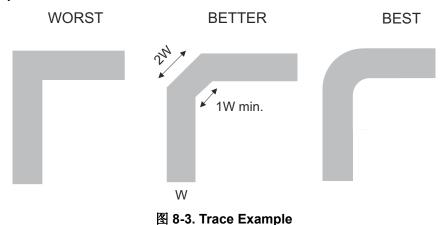


#### 8.4 Layout

#### 8.4.1 Layout Guidelines

Reflections and matching are closely related to loop antenna theory, but different enough to warrant their own discussion. When a PCB trace turns a corner at a 90° angle, a reflection can occur. This reflection is primarily due to the change of width of the trace. At the apex of the turn, the trace width is increased to 1.414 times its width. This upsets the transmission line characteristics, especially the distributed capacitance and self inductance of the trace — resulting in the reflection. It is a given that not all PCB traces can be straight, and so they will have to turn corners. 8 8-3 shows progressively better techniques of rounding corners. Only the last example maintains constant trace width and minimizes reflections.

#### 8.4.2 Layout Example



English Data Sheet: SCHS047

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## 9 Device and Documentation Support

## 9.1 Documentation Support

#### 9.1.1 Related Documentation

For related documentation, see the following:

Texas Instruments, Implications of Slow or Floating CMOS Inputs

## 9.2 接收文档更新通知

要接收文档更新通知,请导航至 ti.com 上的器件产品文件夹。点击*通知* 进行注册,即可每周接收产品信息更改摘要。有关更改的详细信息,请查看任何已修订文档中包含的修订历史记录。

#### 9.3 支持资源

TI E2E™中文支持论坛是工程师的重要参考资料,可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题,获得所需的快速设计帮助。

链接的内容由各个贡献者"按原样"提供。这些内容并不构成 TI 技术规范,并且不一定反映 TI 的观点;请参阅 TI 的使用条款。

#### 9.4 Trademarks

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#### 9.5 静申放申警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序,可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级,大至整个器件故障。精密的集成电路可能更容易受到损坏,这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

#### 9.6 术语表

TI术语表本术语表列出并解释了术语、首字母缩略词和定义。



## **10 Revision History**

注:以前版本的页码可能与当前版本的页码不同

Changes from Revision M (November 2024) to Revision N (February 2025)	Page
• 更新了节 1	1
Removed Figure 5-4 and Figure 5-5	11
• Updated 节 7.1	15
• Updated 节 7.3	17
Updated Figure 8-1 to 5V VDD	19
Changes from Revision L (September 2023) to Revision M (November 2024)	Page
Updated the Typical Characteristics section	
Added Figure 5-4 and Figure 5-5	11
Changes from Revision K (March 2023) to Revision L (September 2023)	Page
• 更改了封装信息表的格式以包含封装引线尺寸	1
• Changed the format of the ESD Ratings, Electrical Characteristics, and AC Performance	
package specifications	5

# 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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English Data Sheet: SCHS047

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## **PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
7901502EA	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	7901502EA CD4052BF3A
8101801EA	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8101801EA CD4053BF3A
CD4051BE	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU   NIPDAU	N/A for Pkg Type	-55 to 125	CD4051BE
CD4051BE.A	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4051BE
CD4051BEE4	Obsolete	Production	PDIP (N)   16	-	-	Call TI	Call TI	-55 to 125	CD4051BE
CD4051BF	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4051BF
CD4051BF.A	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4051BF
CD4051BF3A	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4051BF3A
CD4051BF3A.A	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4051BF3A
CD4051BM96	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4051BM
CD4051BM96.A	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4051BM
CD4051BM96G3	Obsolete	Production	SOIC (D)   16	-	-	Call TI	Call TI	-55 to 125	CD4051BM
CD4051BM96G4	Obsolete	Production	SOIC (D)   16	-	-	Call TI	Call TI	-55 to 125	CD4051BM
CD4051BMT	Obsolete	Production	SOIC (D)   16	-	-	Call TI	Call TI	-55 to 125	CD4051BM
CD4051BNSR	Active	Production	SOP (NS)   16	2000   LARGE T&R	Yes	NIPDAU   NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4051B
CD4051BNSR.A	Active	Production	SOP (NS)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4051B
CD4051BPW	Obsolete	Production	TSSOP (PW)   16	-	-	Call TI	Call TI	-55 to 125	CM051B
CD4051BPWR	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM051B
CD4051BPWR.A	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM051B
CD4051BPWRG4	Obsolete	Production	TSSOP (PW)   16	-	-	Call TI	Call TI	-55 to 125	CM051B
CD4052BE	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU   NIPDAU	N/A for Pkg Type	-55 to 125	CD4052BE
CD4052BE.A	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4052BE
CD4052BEE4	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4052BE
CD4052BF	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4052BF
CD4052BF.A	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4052BF
CD4052BF3A	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	7901502EA CD4052BF3A





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Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	(3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
CD4052BF3A.A	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	7901502EA CD4052BF3A
CD4052BM	Obsolete	Production	SOIC (D)   16	-	-	Call TI	Call TI	-55 to 125	CD4052BM
CD4052BM96	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4052BM
CD4052BM96.A	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4052BM
CD4052BM961G4	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4052BM
CD4052BM961G4.A	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4052BM
CD4052BM96G3	Obsolete	Production	SOIC (D)   16	-	-	Call TI	Call TI	-55 to 125	CD4052BM
CD4052BM96G4	Obsolete	Production	SOIC (D)   16	-	-	Call TI	Call TI	-55 to 125	CD4052BM
CD4052BMT	Obsolete	Production	SOIC (D)   16	-	-	Call TI	Call TI	-55 to 125	CD4052BM
CD4052BNSR	Active	Production	SOP (NS)   16	2000   LARGE T&R	Yes	NIPDAU   NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4052B
CD4052BNSR.A	Active	Production	SOP (NS)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4052B
CD4052BPW	Obsolete	Production	TSSOP (PW)   16	-	-	Call TI	Call TI	-55 to 125	CM052B
CD4052BPWR	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM052B
CD4052BPWR.A	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM052B
CD4052BPWRG3	Obsolete	Production	TSSOP (PW)   16	-	-	Call TI	Call TI	-55 to 125	CM052B
CD4052BPWRG4	Obsolete	Production	TSSOP (PW)   16	-	-	Call TI	Call TI	-55 to 125	CM052B
CD4053BE	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4053BE
CD4053BE.A	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4053BE
CD4053BEE4	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD4053BE
CD4053BF	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4053BF
CD4053BF.A	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	CD4053BF
CD4053BF3A	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8101801EA CD4053BF3A
CD4053BF3A.A	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8101801EA CD4053BF3A
CD4053BM	Obsolete	Production	SOIC (D)   16	-	-	Call TI	Call TI	-55 to 125	CD4053M
CD4053BM96	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4053M
CD4053BM96.A	Active	Production	SOIC (D)   16	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4053M
CD4053BM96G3	Obsolete	Production	SOIC (D)   16	-	-	Call TI	Call TI	-55 to 125	CD4053M
CD4053BM96G4	Obsolete	Production	SOIC (D)   16	-	-	Call TI	Call TI	-55 to 125	CD4053M

-55 to 125

24-Aug-2025

CM053B



CD4053BPWRG4

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					(3)	Ball material	Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
CD4053BMT	Obsolete	Production	SOIC (D)   16	-	-	Call TI	Call TI	-55 to 125	CD4053M
CD4053BNSR	Active	Production	SOP (NS)   16	2000   LARGE T&R	Yes	NIPDAU   NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4053B
CD4053BNSR.A	Active	Production	SOP (NS)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CD4053B
CD4053BPW	Obsolete	Production	TSSOP (PW)   16	-	-	Call TI	Call TI	-55 to 125	CM053B
CD4053BPWR	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM053B
CD4053BPWR.A	Active	Production	TSSOP (PW)   16	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	CM053B
CD4053BPWRG3	Obsolete	Production	TSSOP (PW)   16	-	-	Call TI	Call TI	-55 to 125	CM053B

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Obsolete

Call TI

Call TI

Production

TSSOP (PW) | 16

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

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#### OTHER QUALIFIED VERSIONS OF CD4051B, CD4051B-MIL, CD4052B, CD4052B-MIL, CD4053B, CD4053B-MIL:

● Catalog: CD4051B, CD4052B, CD4053B

• Automotive : CD4051B-Q1, CD4051B-Q1, CD4053B-Q1, CD4053B-Q1

• Military: CD4051B-MIL, CD4052B-MIL, CD4053B-MIL

#### NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military QML certified for Military and Defense Applications



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## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter		A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
00/05/05/05	2010				(mm)	W1 (mm)						
CD4051BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4051BNSR	SOP	NS	16	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1
CD4051BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD4051BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD4052BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4052BM961G4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4052BNSR	SOP	NS	16	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1
CD4052BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD4052BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD4053BM96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD4053BNSR	SOP	NS	16	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1
CD4053BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD4053BPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD4051BM96	SOIC	D	16	2500	353.0	353.0	32.0
CD4051BNSR	SOP	NS	16	2000	353.0	353.0	32.0
CD4051BPWR	TSSOP	PW	16	2000	353.0	353.0	32.0
CD4051BPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
CD4052BM96	SOIC	D	16	2500	353.0	353.0	32.0
CD4052BM961G4	SOIC	D	16	2500	353.0	353.0	32.0
CD4052BNSR	SOP	NS	16	2000	353.0	353.0	32.0
CD4052BPWR	TSSOP	PW	16	2000	353.0	353.0	32.0
CD4052BPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
CD4053BM96	SOIC	D	16	2500	353.0	353.0	32.0
CD4053BNSR	SOP	NS	16	2000	353.0	353.0	32.0
CD4053BPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
CD4053BPWR	TSSOP	PW	16	2000	353.0	353.0	32.0

# **PACKAGE MATERIALS INFORMATION**

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## **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD4051BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4051BE.A	N	PDIP	16	25	506	13.97	11230	4.32
CD4052BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4052BE.A	N	PDIP	16	25	506	13.97	11230	4.32
CD4052BEE4	N	PDIP	16	25	506	13.97	11230	4.32
CD4053BE	N	PDIP	16	25	506	13.97	11230	4.32
CD4053BE.A	N	PDIP	16	25	506	13.97	11230	4.32
CD4053BEE4	N	PDIP	16	25	506	13.97	11230	4.32



SOP



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



SOF



## NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOF



#### NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



# D (R-PDS0-G16)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



## **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



#### 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.



SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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